

# SMD Type 850nm Infrared Emitter

#### **Features**

- Small double-end package
- Viewing Angle =  $\pm 10^{\circ}$
- High radiant intensity
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

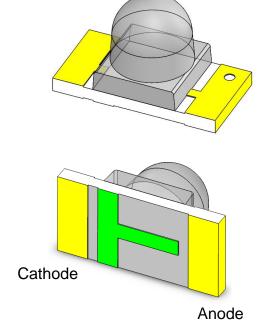
## **Applications**

Infrared sensor

## **Description**

The HIRP3216Q18-C0 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 850nm LED spectrally matched with phototransistor or photodiode.

## **Package Outline**



#### **Schematic**



# HIRP3216Q18-C0 SMD Type 850nm Infrared Emitter

## Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
lF	Continuous Forward Current	70	mA	
I <sub>FP</sub>	Peak Forward Current	0.7	Α	1
VR	Reverse Voltage	5	V	
T <sub>opr</sub>	Operating Temperature	-40 ~ +85	°C	
T <sub>stg</sub>	Storage Temperature	-40 ~ +100	°C	
T <sub>sol</sub>	Soldering Temperature	260	°C	2
P <sub>D</sub>	Power Dissipation at(or below) 25°CFree Air Temperature	140	mW	
R <sub>THJA</sub>	Junction to Ambient Thermal Resistance	540	°C/W	

## Electro-Optical Characteristics TA = 25°C (unless otherwise specified)

#### **Optical Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
le	Radiant Intensity	I <sub>F</sub> =20mA	12.5	20	-	\\\/	-
		I <sub>F</sub> =70mA	-	65	-	mW/sr	
λр	Peak Wavelength	I <sub>F</sub> =20mA	830	850	870	nm	
Δλ	Spectral Bandwidth	I <sub>F</sub> =20mA	-	30	-	nm	
θ1/2	Angle of Half Intensity	I <sub>F</sub> =20mA	-	±10	-	deg	

#### **Electrical Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
V <sub>F</sub> Forward Voltage	I <sub>F</sub> =20mA	1.30	1.40	1.7	V		
	Forward Vollage	I <sub>F</sub> =70mA	1.40	1.56	2.0	] v	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> =5V	-	-	10	μA	

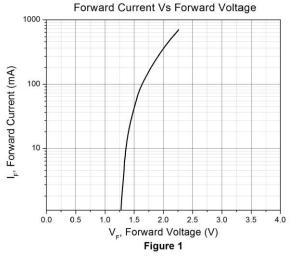
#### Notes:

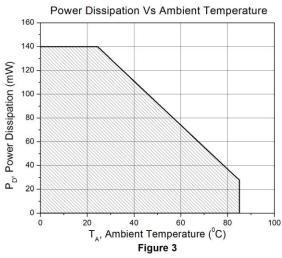
- 1 : I<sub>FP</sub> Conditions--Pulse Width≦ 100µs and Duty≦ 1%.
- 2 : Soldering time  $\leq$  5 seconds.

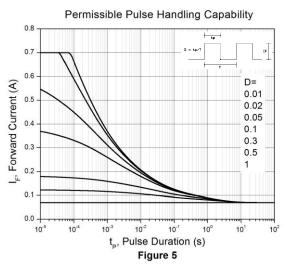


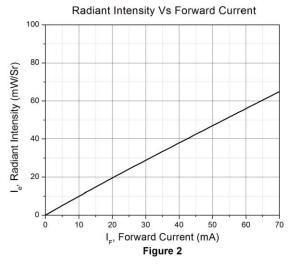
# SMD Type 850nm Infrared Emitter

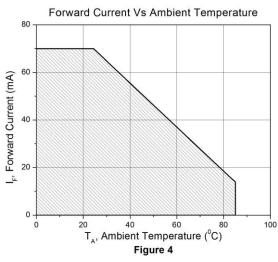
## **Typical Characteristic Curves**

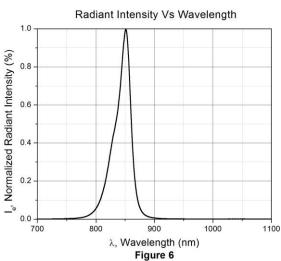










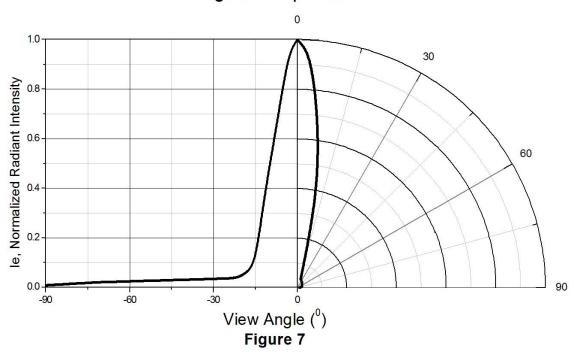




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## **Typical Characteristic Curves**

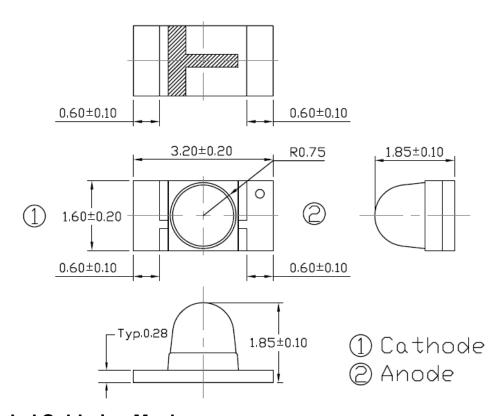
# **Angular Displacement**



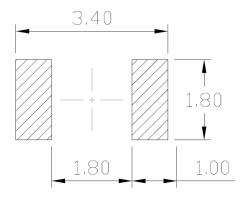


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#### Package Dimension All dimensions are in mm, unless otherwise stated



## Recommended Soldering Mask All dimensions are in mm, unless otherwise stated



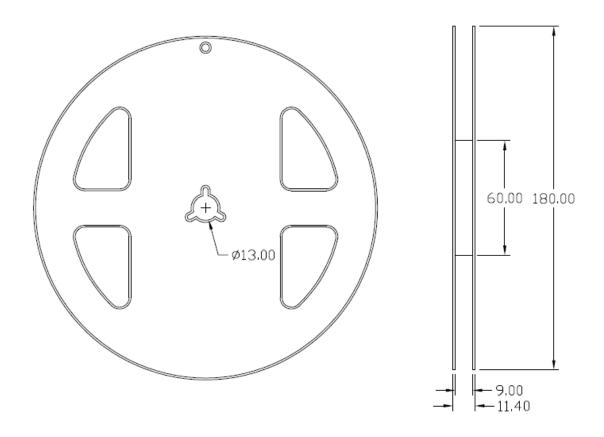
## **Ordering Information**

Part Number	Description	Quantity
HIRP3216Q18-C0(T1)	Tape & Reel	2000 pcs
HIRP3216Q18-C0(T2)	Tape & Reel	2000 pcs



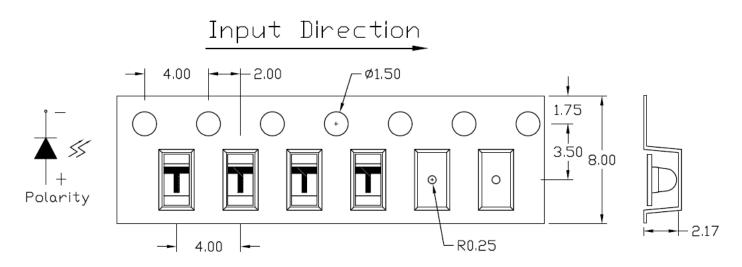
# HIRP3216Q18-C0 SMD Type 850nm Infrared Emitter

## Reel Dimension All dimensions are in mm, unless otherwise stated



## Tape Dimension All dimensions are in mm, unless otherwise stated

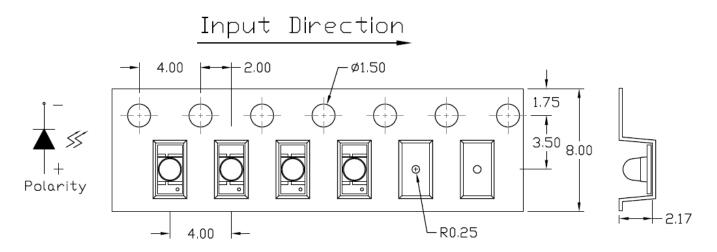
### Part Number HIRP3216Q18-C0(T1)





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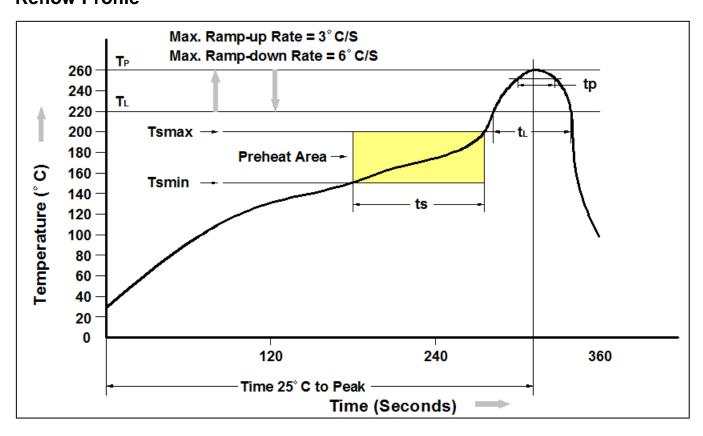
#### Part Number HIRP3216Q18-C0(T2)







#### **Reflow Profile**



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t⊳)	3°C/second max.
Liquidous Temperature (T∟)	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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